AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions and listings of claims in the application:

1. (presently amended) A light-emissive device comprising:

a light-emissive region;

a first electrode located on a viewing side of the light-emissive region for injecting charge carriers of a first type; and

a second electrode located on a non-viewing side of the light-emissive region for injecting charge carriers of a second type;

and wherein there is a reflectivity-influencing structure located on the non-viewing side of the light-emissive region and including a light absorbent layer comprising [graphite and/or a fluoride or oxide of a low work function metal] a fluoride or oxide of a metal having a work function of 3.5 eV or less.

2. (original) A light-emissive device as claimed in claim 1, wherein the first electrode is at least partially light-transmissive.

3. (previously amended) A light-emissive device as claimed in claim 1, wherein the reflectivity influencing structure is located on the opposite side of the second electrode from the light-emissive region.

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4. (original) A light-emissive device as claimed in claim 3, wherein the second electrode is at least partially light-transmissive.

5. (previously amended) A light-emissive device as claimed in claim 3, wherein the thickness of the second electrode is less than 30nm.

6. (previously amended) A light-emissive device as claimed in claim 3, wherein the reflectivity-influencing structure is adjacent the second electrode.

7. (previously amended) A light-emissive device as claimed in claim 1, wherein the second electrode provides the reflectivity-influencing structure.

8. (original) A light-emissive device as claimed in claim 7, wherein the second electrode comprises a fluoride or oxide of a low work function metal.

9. (original) A light-emissive device as claimed in claim 8, wherein the second electrode comprises aluminium.

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10. (previously amended) A light-emissive device as claimed in claim 1, wherein the reflectivity-influencing structure is effective to absorb light emitted from the light-emissive region that reaches it through the second electrode and/or incident light.

11. (previously amended) A light-emissive device as claimed in claim 7, wherein the presence of the reflectivity-influencing structure adjacent the second electrode renders that second electrode substantially non-reflective to light emitted form the light-emissive region and/or incident light.

12. (previously amended) A light-emissive device as claimed in claim 1, wherein the second electrode comprises an electrically conductive material.

13. (presently amended) A light-emissive device as claimed in claim 1, wherein the light-emissive [layer] region comprises an organic light-emissive material.

14. (presently amended) A light-emissive device as claimed in claim 1, wherein the light-emissive [layer] region comprises a polymer light-emissive material.

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15. (presently amended) A light-emissive device as claimed in claim 1, wherein the light-emissive [layer] region comprises a conjugated polymer material.

16. (presently amended) A light-emissive device as claimed in claim 1, wherein the reflecti[on]vity-influencing r is electrically conductive.

17.-27. (canceled)

28. (presently amended) [A light-emissive device as claimed in claim 26,] A light-emissive device comprising:

a light-emissive region;

a first electrode located on a viewing side of the light-emissive region for injecting charge carriers of a first type;

a second electrode located on a non-viewing side of the light-emissive region for injecting charge carriers of a second type;

and a contrast enhancing structure located on the non-viewing side of the light-emissive region and including a reflective structure having different reflectivity for different wavelengths of incident light, and having a reflectivity peak encompassing an emission wavelength of the light-emissive region,

wherein the second electrode comprises a layer located on the non-viewing side of the reflective structure and a plurality of through paths passing through the reflective structure for electrical conduction between the said layer of the second electrode and the light-emissive region.

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29. (original) A light-emissive device as claimed in claim 28, wherein the though paths occupy less than 15% of the emissive area of the device.

30. (canceled)

31. (presently amended) A light-emissive device as claimed in claim [30] 28, wherein the second electrode comprises a transparent layer located between the reflective structure and the light-emissive region, and the transparent layer is in contact with the through paths.

32.-34. (canceled)

35. (presently amended) A light-emissive device as claimed in claim [26] 28, wherein the light-emissive [layer] region comprises a conjugated polymer material.

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